NSN 5961-00-835-6448

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-00-835-6448

Inclosure Material:

Metal

Overall Length:

Between 0.240 inches and 0.260 inches

Terminal Length:

1.500 inches

Overall Diameter:

Between 0.335 inches and 0.370 inches

Internal Configuration:

Unijunction

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 emitter to base voltage, dc

Current Rating Per Characteristic:

70.00 milliamperes repetitive peak forward current megahertz and 2.00 microamperes repetitive peak forward current nanoamperes

Power Rating Per Characteristic:

600.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pn

Precious Material And Location:

Terminal surfaces gold

Precious Material:

Gold

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/75 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

